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Vishay Semiconductor/Diodes Division 10TQ040

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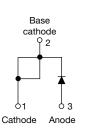


### VS-10TQ...PbF Series, VS-10TQ...-N3 Series

**Vishay Semiconductors** 

# Schottky Rectifier, 10 A





**TO-220AC** 

PRODUCT SUMMARY							
Package	TO-220AC						
I <sub>F(AV)</sub>	10 A						
V <sub>R</sub>	35 V, 40 V, 45 V						
V <sub>F</sub> at I <sub>F</sub>	0.49 V						
I <sub>RM</sub>	15 mA at 125 °C						
T <sub>J</sub> max.	175 °C						
Diode variation	Single die						
E <sub>AS</sub>	13 mJ						

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#### **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



RoHS

FREE

- COMPLIANT HALOGEN · Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### DESCRIPTION

The VS-10TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	10	A						
V <sub>RRM</sub>		35/45	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1050	А						
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.49	V						
TJ	Range	- 55 to 175	°C						

VOLTAGE RATINGS										
PARAMETER	SYMBOL	VS- 10TQ035PbF	VS- 10TQ035-N3	VS- 10TQ040PbF	VS- 10TQ040-N3	VS- 10TQ045PbF	VS- 10TQ045-N3	UNITS		
Maximum DC reverse voltage	V <sub>R</sub>		35	40	40	45	45	V		
Maximum working peak reverse voltage	V <sub>RWM</sub>	35								

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS					
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at $T_C = 151$ °C	10							
Maximum peak one cycle non-repetitive surge current	Isou	5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and with rated	1050	А					
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	280						
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 6.5 n	13	mJ						
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to ze Frequency limited by T <sub>J</sub> maxin	2	А						

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Document Number: 94120





# VS-10TQ...PbF Series, VS-10TQ...-N3 Series

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
		10 A	T <sub>.1</sub> = 25 °C	0.57					
Maximum forward voltage drop See fig. 1	V <sub>FM</sub> <sup>(1)</sup>	20 A	1j=25 C	0.67	v				
	VFM (*)	10 A	T.I = 125 °C	0.49	v				
		20 A	1j = 125 C	0.61					
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	$T_J = 25 \ ^\circ C$	$V_{\rm B}$ = Rated $V_{\rm B}$	2	mA				
See fig. 2	IRM (")	T <sub>J</sub> = 125 °C	$v_{\rm R}$ = naleu $v_{\rm R}$	15	ША				
Maximum junction capacitance	CT	$V_{R}$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		900	pF				
Typical series inductance	L <sub>S</sub>	Measured lead to lead 5 r	8.0	nH					
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>		10 000	V/µs				

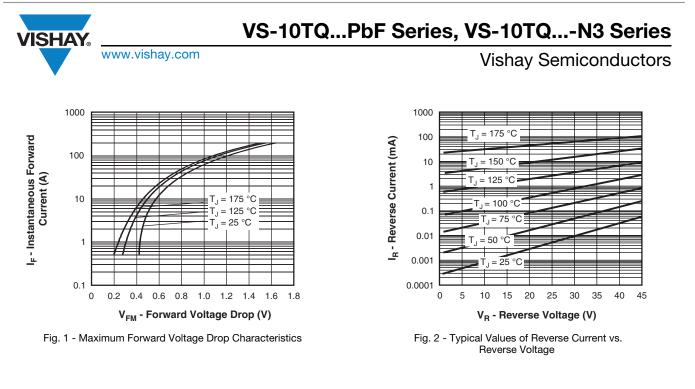
#### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C				
Maximum thermal resistan junction to case	ce,	R <sub>thJC</sub>	DC operation See fig. 4	2.0	°C/W				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.50	°C/W				
Approvimate weight				2	g				
Approximate weight				0.07	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque	maximum			12 (10)	(lbf ⋅ in)				
Marking daviaa				10T0	2035				
Marking device			Case style TO-220AC	10TQ045					

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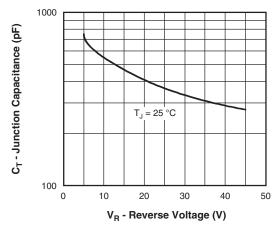
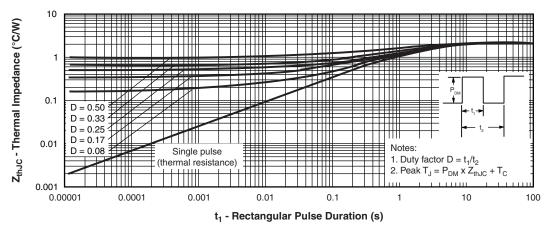


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage





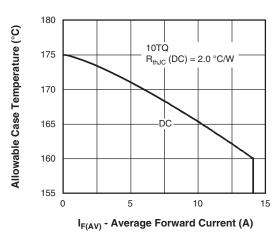
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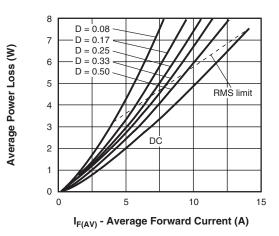
# VS-10TQ...PbF Series, VS-10TQ...-N3 Series

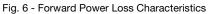
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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current





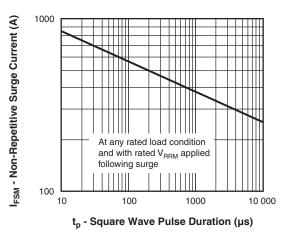


Fig. 7 - Maximum Non-Repetitive Surge Current

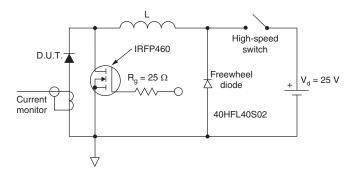


Fig. 8 - Unclamped Inductive Test Circuit

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## VS-10TQ...PbF Series, VS-10TQ...-N3 Series

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#### **ORDERING INFORMATION TABLE**

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							-
Device code	VS-	10	т	Q	045	PbF	
	1	2	3	4	5	6	-
	1 2 3 -	- Cur Pac T =	rent rati kage: TO-220		= 10 A)	oduct	
	4 - 5 - 6 -	Volt	age rati	≀" series ngs — ntal digit			035 = 35 V 040 = 40 V 045 = 45 V
		• F	bF = Le	ad (Pb)	-free an		S compliant

-N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-10TQ035PbF	50	1000	Antistatic plastic tube							
VS-10TQ035-N3	50	1000	Antistatic plastic tube							
VS-10TQ040PbF	50	1000	Antistatic plastic tube							
VS-10TQ040-N3	50	1000	Antistatic plastic tube							
VS-10TQ045PbF	50	1000	Antistatic plastic tube							
VS-10TQ045-N3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Daut na andria a infanna atian	TO-220ACPbF	www.vishay.com/doc?95224				
Part marking information	TO-220AC-N3	www.vishay.com/doc?95068				

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### **Outline Dimensions**

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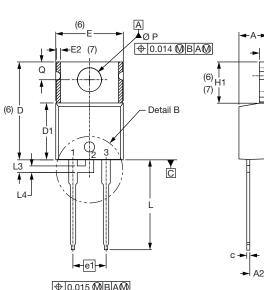
**TO-220AC** 

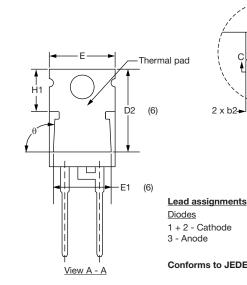
В Seating

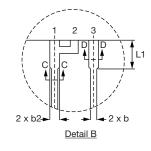
+A1

plane A-

#### **DIMENSIONS** in millimeters and inches









1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

♦ 0.015 Ø B A Ø

SYMBOL	MILLIN	IETERS	INC	HES	NOTES	OTES SYM		MILLIN	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040			e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4		H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068			L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4		L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024			L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4		L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3		ØΡ	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6		θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6							

#### Notes

 $^{(1)}\,$  Dimensioning and tolerancing as per ASME Y14.5M-1994  $\,$ 

(2) Lead dimension and finish uncontrolled in L1

<sup>(3)</sup> Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- <sup>(4)</sup> Dimension b1, b3 and c1 apply to base metal only
- <sup>(5)</sup> Controlling dimension: inches
- <sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1
- $^{(7)}\,$  Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- <sup>(8)</sup> Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline





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